



60V N-CHANNEL ENHANCEMENT MODE MOSFET

100% Unclamped Inductive Switch (UIS) test in production

Case Material: Molded Plastic, "Green" Molding Compound. UL

Terminals: Matte Tin Finish annealed over Copper leadframe.

Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) Qualified to AEC-Q101 Standards for High Reliability

Flammability Classification Rating 94V-0 (Note 1)

Moisture Sensitivity: Level 1 per J-STD-020

Solderable per MIL-STD-202, Method 208 Weight: 0.33 grams (approximate)

Terminals Connections: See Diagram

Features and Benefits

Low on-resistance Fast switching speed

Mechanical Data
 Case: TO252

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D T _A = +25°C
60V	$68m\Omega @ V_{GS} = 10V$	8.5A
	100m Ω @ V _{GS} = 4.5V	7.0A

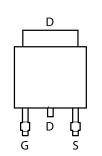
Description

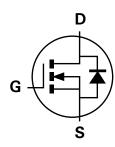
This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- Transformer Driving Switch
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply







PIN OUT -TOP VIEW

Equivalent Circuit

Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN6068LK3-13	N6068L	13	16	2,500

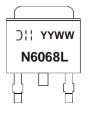
Note: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

Marking Information





Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic Drain-Source voltage			Symbol	Value	Unit
			V _{DSS}	60	V
Gate-Source voltage (Note 5)		(Note 5)	V _{GS}	±20	V
Single Pulsed Avalanche Energy (Note 11)		(Note 11)	Eas	37.5	mJ
Single Pulsed Avalanche Current (Note 11)		(Note 11)	I _{AS}	5.0	А
		(Note 7)		8.5	
Continuous Drain current	$V_{GS} = 10V$	$T_{A} = 70^{\circ}C$ (Note 7)	ID	6.8	A
		(Note 6)		6.0	
Pulsed Drain current	V _{GS} = 10V	(Note 8)	IDM	22.2	A
Continuous Source current (Body diode) (Note 7)		(Note 7)	Is	10.2	А
Pulsed Source current (Body diode) (Note 8)		I _{SM}	22.2	А	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 6)		4.12 33	
Power dissipation Linear derating factor	(Note 7)	PD	8.49 67.9	₩ mW/°C
	(Note 9)		2.12 16.9	
	(Note 6)		30.3	
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	14.7	0000
	(Note 9)		59.0	°C/W
Thermal Resistance, Junction to Lead	(Note 10)	R _{θJL}	3.09	
Operating and storage temperature range		T _J , T _{STG}	-55 to +150	°C

Notes: 5. AEC-Q101 V_{GS} maximum is $\pm 16V.$

6. For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

7. Same as note 2, except the device is measured at t \leq 10 sec.

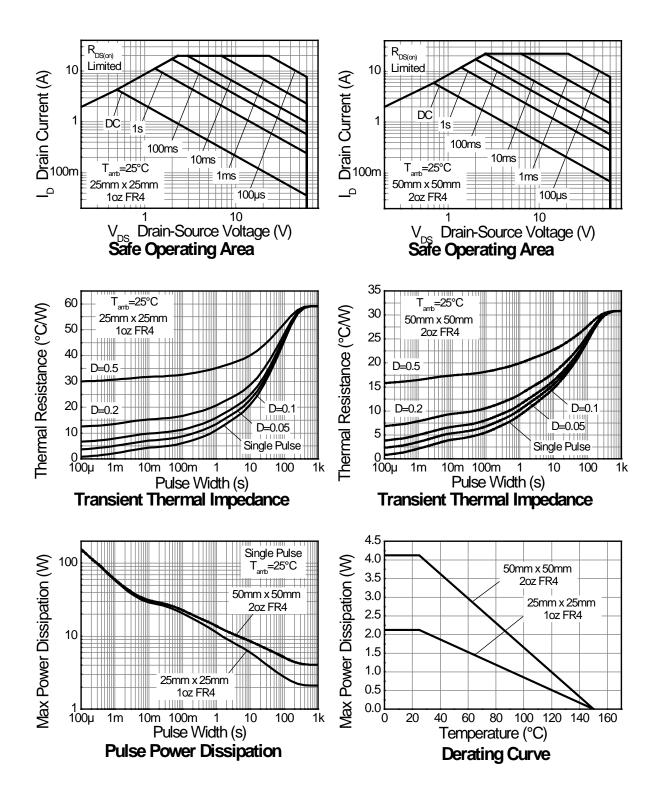
8. Same as note 2, except the device is pulsed with D = 0.02 and pulse width 300 µs. The pulse current is limited by the maximum junction temperature. 9. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

10. Thermal resistance from junction to solder-point (at the end of the drain lead).

11. UIS in production with L = 3.0mH, I_{AS} = 5.0Å, R_G = 25• , V_{DD} = 50V, starting T_J = 25°C



Thermal Characteristics





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

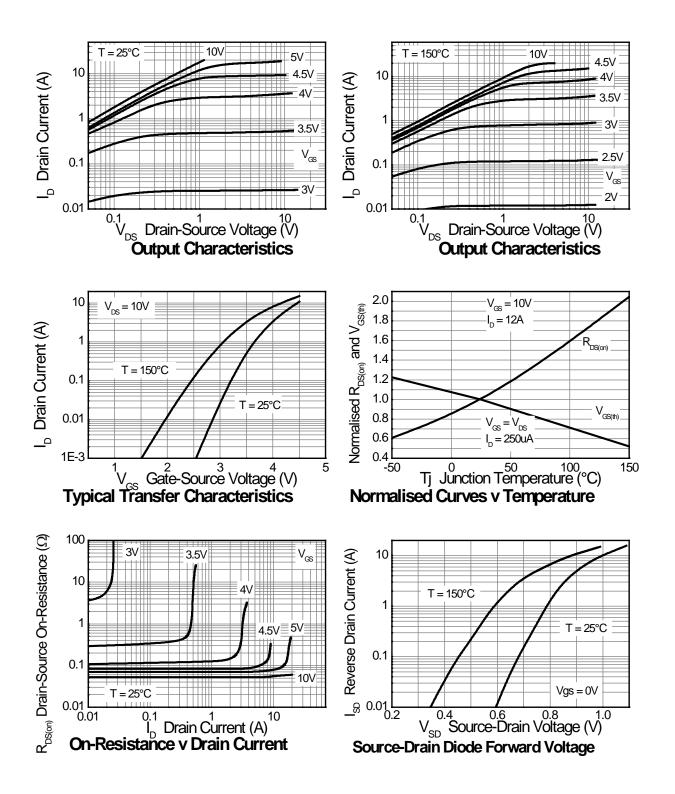
Characteristic	Symbol	Min	Тур	Max	Unit	Test	Condition
OFF CHARACTERISTICS			•	•			
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	I _D = 250μA, V _{GS} = 0V	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	0.5	μA	V_{DS} = 60V, V_{GS}	= 0V
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	V _{GS} = ±20V, V _{DS} = 0V	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	1.0	_	3.0	V	I _D = 250μA, V _{DS}	s= V _{GS}
Static Drain-Source On-Resistance (Note 12)	Р			0.068	Ω	V_{GS} = 10V, I_{D} =	12A
	R _{DS (ON)}	_	_	0.100	52	V_{GS} = 4.5V, I_{D} =	6A
Forward Transconductance (Notes 12 & 13)	g fs	_	19.7	_	S	V _{DS} = 15V, I _D = 12A	
Diode Forward Voltage (Note 12)	V _{SD}	_	0.98	1.15	V	I _S = 12A, V _{GS} = 0V	
Reverse recovery time (Note 13)	t _{rr}		145	_	ns	—I _S = 12A, di/dt= 100A/μs	
Reverse recovery charge (Note 13)	Q _{rr}	_	929	_	nC		
DYNAMIC CHARACTERISTICS (Note 13)							
Input Capacitance	C _{iss}	_	502	_	pF	V _{DS} = 30V, V _{GS} = 0V f= 1MHz	
Output Capacitance	C _{oss}	_	45.7	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	27.1	_	pF		
Total Gate Charge	Qg	_	5.55	_	nC	V _{GS} = 4.5V	
Total Gate Charge	Qg	_	10.3	_	nC		V _{DS} = 30V
Gate-Source Charge	Q _{gs}	_	1.6	_	nC	V _{GS} = 10V	I _D = 12A
Gate-Drain Charge	Q _{gd}	_	3.5		nC	┨ │ │	
Turn-On Delay Time (Note 14)	t _{D(on)}	_	3.6	_	ns		
Turn-On Rise Time (Note 14)	tr	_	10.8	_	ns	V_{DD} = 30V, V_{GS} = 10V I_D = 12A, $R_G \cong 6.0\Omega$	
Turn-Off Delay Time (Note 14)	t _{D(off)}		11.9		ns		
Turn-Off Fall Time (Note 14)	t _f	_	8.7	_	ns	1	

Notes:

12. Measured under pulsed conditions. Pulse width \leq 300 μ s; duty cycle \leq 2% 13. For design aid only, not subject to production testing. 14. Switching characteristics are independent of operating junction temperatures.

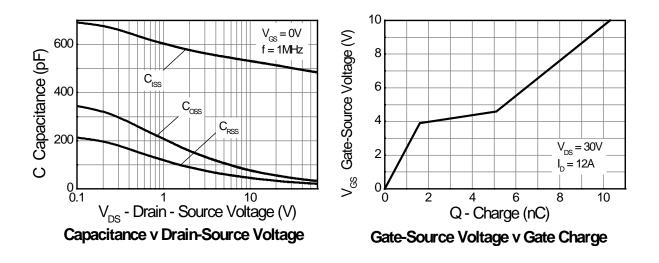


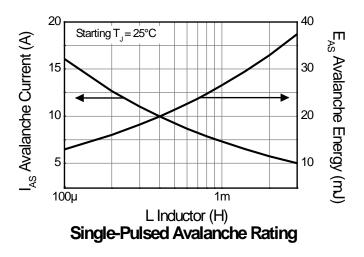
Typical Characteristics





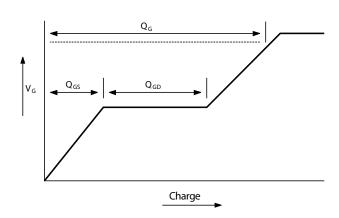
Typical Characteristics - continued



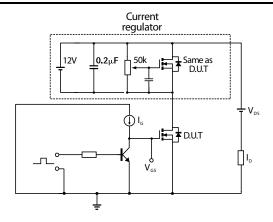




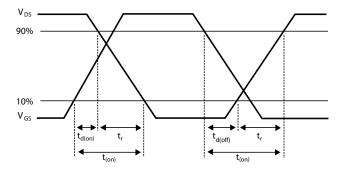
Test Circuits



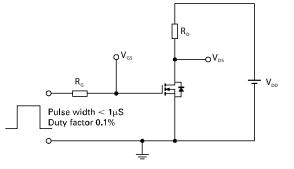
Basic gate charge waveform







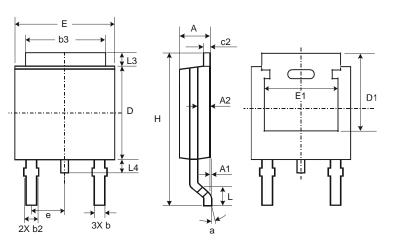
Switching time waveforms



Switching time test circuit

Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

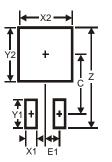


TO252					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
c2	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	_		
All Dimensions in mm					



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
С	6.9
E1	2.3

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